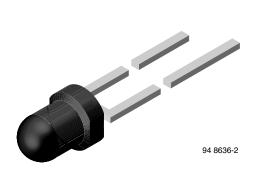
HALOGEN FREE

GREEN



Vishay Semiconductors

Silicon NPN Phototransistor



DESCRIPTION

TEFT4300 is a silicon NPN phototransistor with high radiant sensitivity in black, T-1 plastic package with daylight blocking filter. Filter bandwidth is matched with 900 nm to 950 nm IR emitters.

FEATURES

Package type: leadedPackage form: T-1

• Dimensions (in mm): Ø 3

- High radiant sensitivity
- Daylight blocking filter matched with 940 nm emitters
- Fast response times
- Angle of half sensitivity: $\varphi = \pm 30^{\circ}$
- Package matched with IR emitter series TSUS4300 and TSAL4400
- Material categorization: for definitions of compliance please see <u>www.vishay.com/doc?99912</u>



- Optical switches
- · Counters and sorters
- Interrupters
- Encoders
- · Position sensors

| PRODUCT SUMMARY | | | | |
|-----------------|----------------------|---------|-----------------------|--|
| COMPONENT | I _{ca} (mA) | φ (deg) | λ _{0.5} (nm) | |
| TEFT4300 | 3.2 | ± 30 | 875 to 1000 | |

Note

· Test condition see table "Basic Characteristics"

| ORDERING INFORMATION | | | | | |
|----------------------|-----------|------------------------------|--------------|--|--|
| ORDERING CODE | PACKAGING | REMARKS | PACKAGE FORM | | |
| TEFT4300 | Bulk | MOQ: 5000 pcs, 5000 pcs/bulk | T-1 | | |

Note

• MOQ: minimum order quantity

| ABSOLUTE MAXIMUM RATINGS (T _{amb} = 25 °C, unless otherwise specified) | | | | | |
|----------------------------------------------------------------------------------------|----------------------------------------------|-------------------|-------------|------|--|
| PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT | |
| Collector emitter voltage | | V _{CEO} | 70 | V | |
| Emitter collector voltage | | V _{ECO} | 5 | V | |
| Collector current | | I _C | 50 | mA | |
| Collector peak current | $t_p/T = 0.5, t_p \le 10 \text{ ms}$ | I _{CM} | 100 | mA | |
| Power dissipation | T _{amb} ≤ 55 °C | P _V | 100 | mW | |
| Junction temperature | | Tj | 100 | °C | |
| Operating temperature range | | T _{amb} | -40 to +100 | °C | |
| Storage temperature range | | T _{stg} | -40 to +100 | °C | |
| Soldering temperature | $t \le 3$ s, 2 mm from case | T _{sd} | 260 | °C | |
| Thermal resistance junction/ambient | Connected with Cu wire, 0.14 mm ² | R _{thJA} | 450 | K/W | |



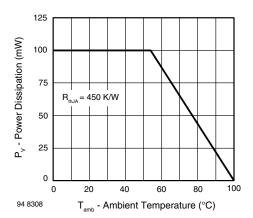


Fig. 1 - Power Dissipation Limit vs. Ambient Temperature

| BASIC CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | |
|-------------------------------------------------------------------------------------|---------------------------------------------------------------------------------|----------------------|------|-------------|------|------|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT |
| Collector emitter breakdown voltage | I _C = 1 mA | V _{(BR)CEO} | 70 | | | V |
| Collector emitter dark current | $V_{CE} = 20 \text{ V}, E = 0$ | I _{CEO} | | 1 | 200 | nA |
| Collector emitter capacitance | $V_{CE} = 5 \text{ V, f} = 1 \text{ MHz, E} = 0$ | C _{CEO} | | 3 | | pF |
| Collector light current | $E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$, $V_{CE} = 5 \text{ V}$ | I _{ca} | 0.8 | 3.2 | | mA |
| Angle of half sensitivity | | φ | | ± 30 | | deg |
| Wavelength of peak sensitivity | | λ_{p} | | 925 | | nm |
| Range of spectral bandwidth | | λ _{0.5} | | 875 to 1000 | | nm |
| Collector emitter saturation voltage | $E_e = 1 \text{ mW/cm}^2$, $\lambda = 950 \text{ nm}$, $I_C = 0.1 \text{ mA}$ | V _{CEsat} | | | 0.3 | V |
| Turn-on time | $V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$ | t _{on} | | 2 | | μs |
| Turn-off time | $V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$ | t _{off} | | 2.3 | | μs |
| Cut-off frequency | $V_S = 5 \text{ V}, I_C = 5 \text{ mA}, R_L = 100 \Omega$ | f _c | | 180 | | kHz |

BASIC CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

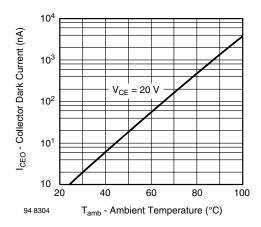


Fig. 2 - Collector Dark Current vs. Ambient Temperature

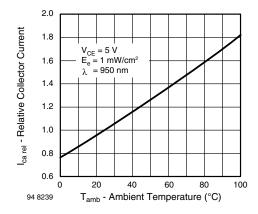


Fig. 3 - Relative Collector Current vs. Ambient Temperature

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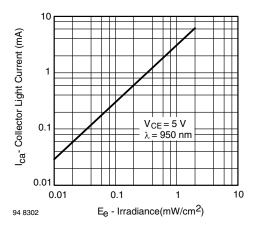


Fig. 4 - Collector Light Current vs. Irradiance

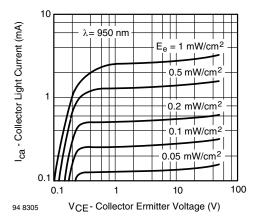


Fig. 5 - Collector Light Current vs. Collector Emitter Voltage

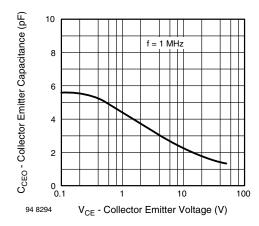


Fig. 6 - Collector Emitter Capacitance vs. Collector Emitter Voltage

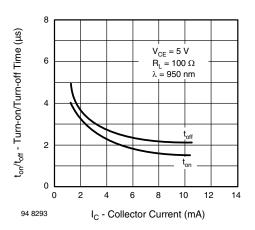


Fig. 7 - Turn-on/Turn-off Time vs. Collector Current

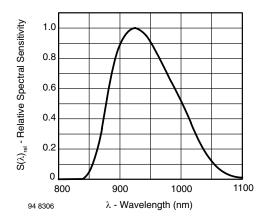


Fig. 8 - Relative Spectral Sensitivity vs. Wavelength

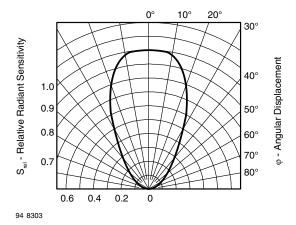
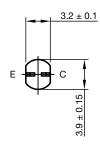


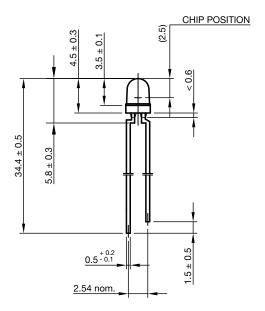
Fig. 9 - Relative Radiant Sensitivity vs. Angular Displacement

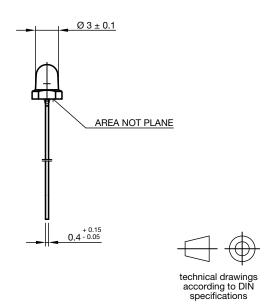


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PACKAGE DIMENSIONS in millimeters







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